TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP624, TLP624-2, TLP624-4

Programmable Controllers AC/DC-Input Module Telecommunication

The TOSHIBA TLP624, -2 and -4 consist of a gallium arsenide infrared emitting diode optically coupled to a photo-transistor.

The TLP624–2 offers two isolated channels in an eight lead plastic DIP, while the TLP624–4 provides four isolated channels in a sixteen plastic DIP.

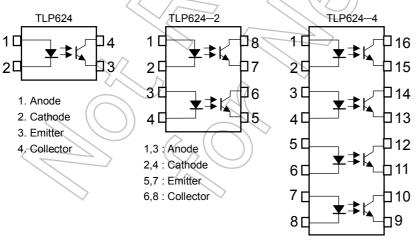
- Collector-emitter voltage: 55V (min)
- Current transfer ratio

Classification	Curre	Marking		
	Ta =	25°C	Ta=-25~75°C	Marking
Classification	I _F =1mA V _{CE} =0.5V	I _F =0.5mA V _{CE} =1.5V	I _F =1mA V _{CE} =0.5V	classification
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, blank

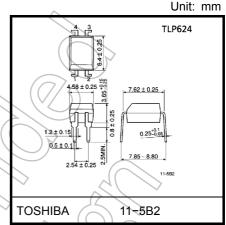
- Isolation voltage: 5000V_{rms} (min)
- UL recognized: UL1577, file No.E67349
- BSI approved: BS EN60065: 2002 Certificate No.7426
 BS EN60950-1: 2002 Certificate No.7427
- Note: Application type name for certification test, please use standard product type name, i.e.

TLP624(BV): TLP624 TLP624-2(BV): TLP624-2

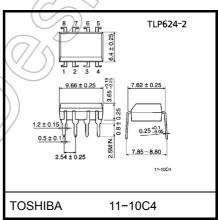
Pin Configurations (top view)



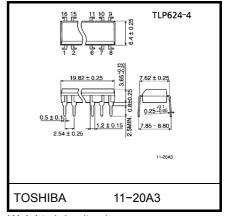
1,3,5,7: Anode 2,4,6,8: Cathode 9,11,13,15: Emitter 10,12,14,16: Collector



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1986/04



Absolute Maximum Ratings (Ta = 25°C)

	2		Ra	ting	
	Characteristic	Symbol	TLP624	TLP624-2 TLP624-4	Unit
	Forward current	lF	60	50	mA
	Forward current detating	ΔI _F / °C	–0.7(Ta ≥ 39°C)	–0.5(Ta ≥ 25°C)	mA / °C
	Pulse forward current	I _{FP}	1 (100µs, pu	ilse, 100pps)	Α
LED	Power dissipation (1 circuit)	P _D	100	70	mW
	Power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _D / °C	-1.0	 0.7	mW/°C
	Reverse voltage	V _R	$\langle (/ /) \rangle$	5	V
	Junction temperature	Tj		25	°C
	Collector–emitter voltage	V _{CEO}	5	55	V
	Emitter–collector voltage	V _{ECO}		7	V
Detector	Collector current	IÇ	5	00	mA
Dete	Collector power dissipation (1 circuit)	Pc	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _C / °C	-1/5	O) _{-1.0}	mW/°C
	Junction temperature	\\Tj	1:	25	°C
Stora	age temperature range	T _{stg}	-55~125		°C
Ope	rating temperature range	Popr	-55	-100	°C
Lead	I soldering temperature	T _{sol}	260	(10s)	°C
Tota	I package power dissipation (1 circuit)	Рт	250	150	mW
Tota	I package power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP _T / °C	-2.5	-1.5	mW/°C
Isola	tion voltage (Note 1)	BVs	5000 (AC, 1 mir	nute, R.H.≤60%)	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: LED side pins shorted together, and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Voc	_	5	24	٧
Forward current	T _E	_	1.6	20	mA
Collector current	Ic	_	1	10	mA
Operating temperature	T _{opr}	-25	_	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1MHz	_ <	30	-	pF
	Collector–emitter breakdown voltage	V _{(BR)CEO}	I _C = 0.5mA	55			V
ď	Emitter–collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1mA	7		1	V
Detector	Collector dark current	lana	V _{CE} = 24V	6	10	100	nA
ă	Soliector dark current	ICEO	V _{CE} = 24V, Ta = 85°C) 2	50	μA
	Capacitance collector to emitter	C _{CE}	V=0 , f=1MHz	1	12	-	pF

Coupled Electrical Characteristics (Ta = 25°C)

					/ // /	
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	I _C / I _F	$I_F = 1$ mA, $V_{CE} = 0.5$ V Rank BV	100	1	1200 1200	%
Low input CTR	I _C / I _{F (low)}	$I_F = 0.5$ mA, $V_{CE} = 1.5$ V Rank BV	50 100		⁻	%
		$I_C = 0.5 \text{mA}, I_F = 1 \text{mA}$	(7/5)		0.4	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 1mA, I _F = 1mA		0.2	_	V
		Rank BV	//-	_	0.4	

Coupled Electrical Characteristics (Ta = -25°C~75°C)

Character	istic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	O _C /I _F	$I_F = 1 \text{mA}, V_{CE} = 0.5 \text{V}$	50	_	_	%	
) I I	Rank B	V 100	_	ı	70	
Low input CTR		$I_F = 0.5 \text{mA}, V_{CE} = 1.5 \text{V}$	_	50	ı	%	
	I _C / I _{F (low)}	Rank B	v _	100	_	70	





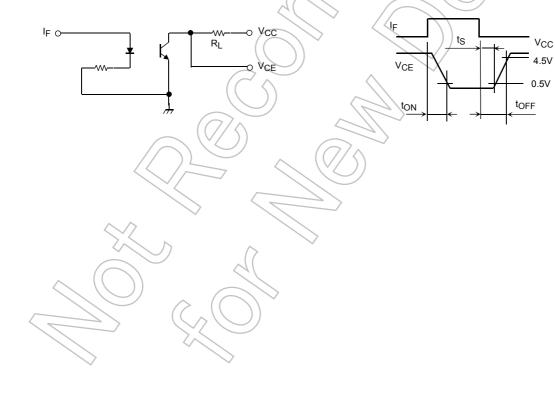
Isolation Characteristics (Ta = 25°C)

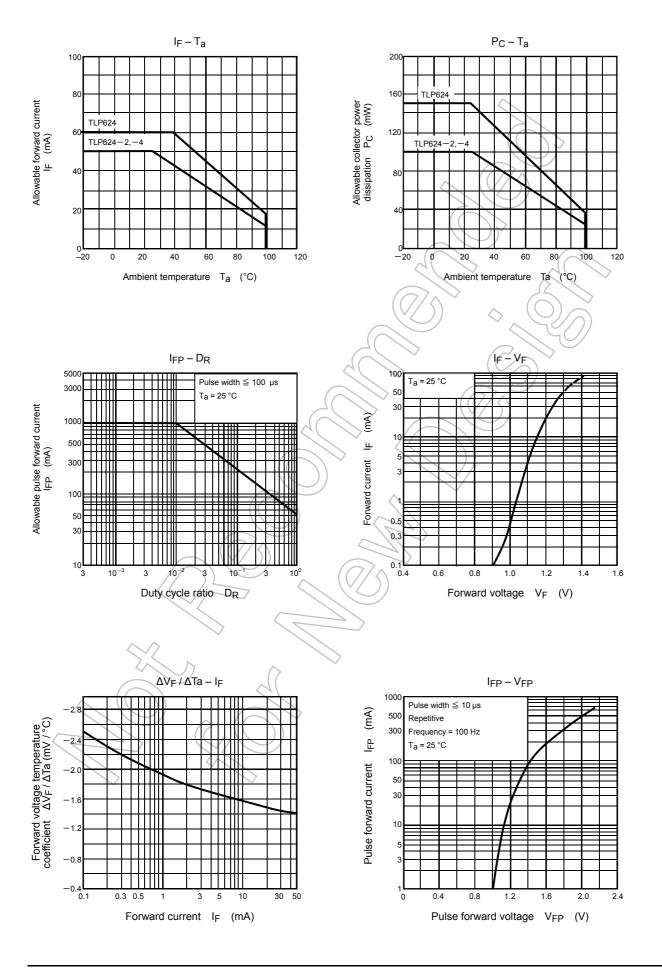
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0, f = 1MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1minute	5000	\ -	_	Vrms
Isolation voltage	BV_S	AC, 1second, in oil	_	10000	_	VIIIIS
		DC, 1 minute, in oil	_	10000)~-	Vdc

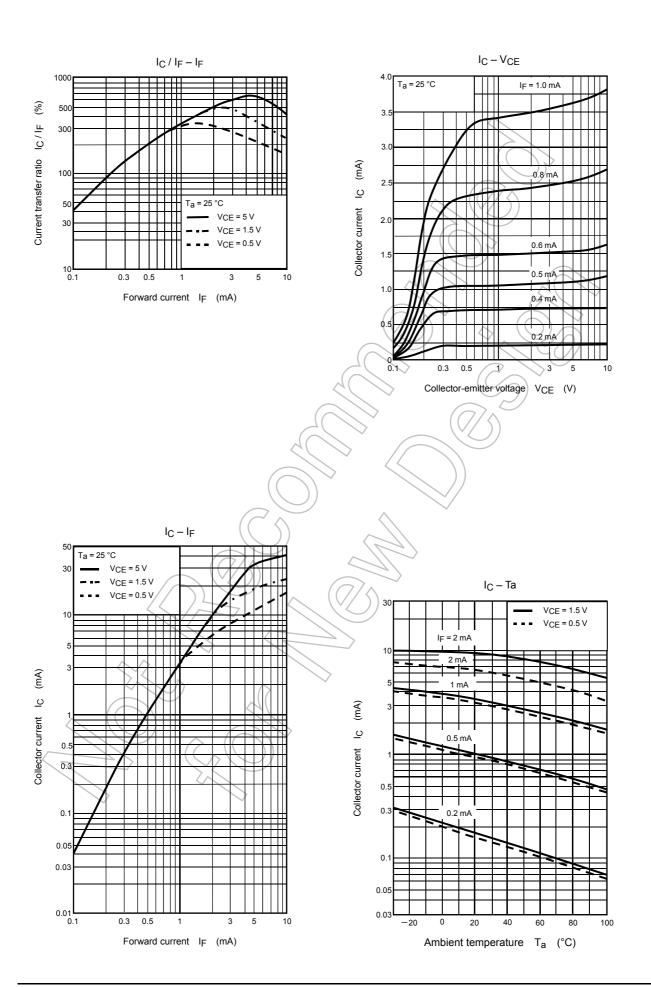
Switching Characteristics (Ta = 25°C)

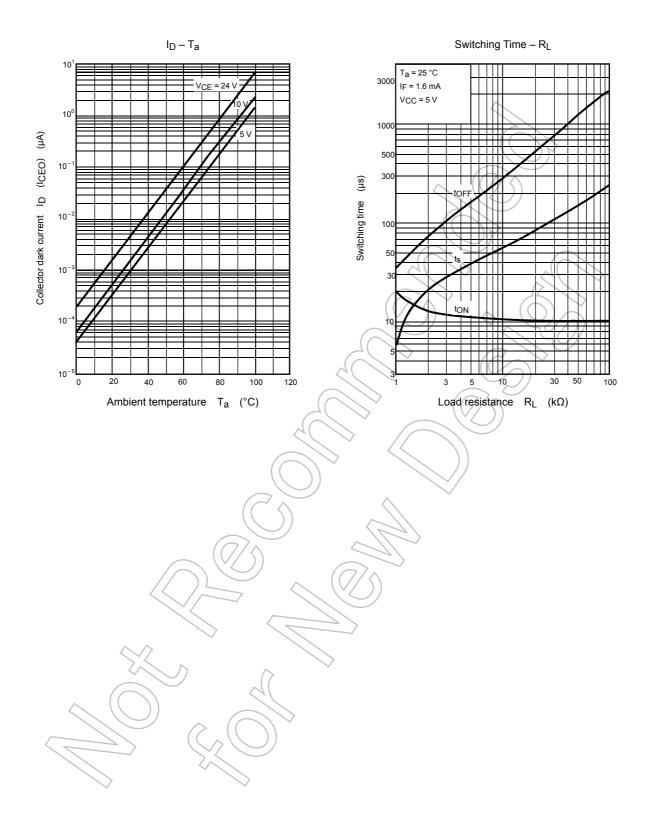
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Rise time	t _r			8		/	
Fall time	t _f	$V_{CC} = 10V$, $I_C = 2mA$ $R_L = 100\Omega$	_	8 _	77		
Turn-on time	t _{on}		· _	10	/-//	μs	
Turn-off time	t _{off}		-0	8)	
Turn-on time	t _{ON}		-	10			
Storage time	t _S	R_L = 4.7 kΩ (Fig.1) V_{CC} = 5 V, I_F = 1.6mA	-((50	⁷ –	μs	
Turn-off time	toff	33		300	_		

Fig. 1 Switching time test circuit









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